NTNU

TTT4205 MICROWAVE TECHNIQUES

Waveguide assignment

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1 Rectangular waveguide

1.1 Cut-off frequencies

The cut-off frequency of a hollow waveguide is given by

$$f_{\rm c}^{\rm (mn)} = \frac{c}{2\pi\sqrt{\epsilon_{\rm r}\mu_{\rm r}}}\sqrt{\left(\frac{m\pi}{a}\right)^2 + \left(\frac{n\pi}{b}\right)^2}.$$
 (1)

For a WR75 waveguide, modes TE_{10} and TE_{20} , the cut-off frequencies are $f_c^{(10)}=7.8740\,\mathrm{GHz}$ and $f_c^{(20)}=15.748\,\mathrm{GHz}$.

The unimodal frequency band, ΔF , is given by

$$\Delta F = f_c^{(20)} - f_c^{(10)} = 7.8740 \,\text{GHz}.$$
 (2)

1.2 Normalized propagation constants

The propagation constant of a hollow waveguide is given by

$$k_{\rm z}^{\rm (mn)} = \sqrt{k_0^2 \epsilon_{\rm r} \mu_{\rm r} - \left(\frac{m\pi}{a}\right)^2 - \left(\frac{n\pi}{b}\right)^2} \tag{3}$$

where

$$k_0 = \frac{2\pi f}{c} = \frac{2\pi f}{3 \times 10^8 \,\text{m/s}}.\tag{4}$$

For a WR75 waveguide, modes TE_{10} and TE_{20} , from 5 to 25 GHz, the propagation constants are shown in figure 1.

1.3 Phase and group velocities

The phase and group velocities for the TE_{10} mode in the unimodal frequency band is given by equations 5 and 6 and plotted in figure 2.

$$V_{\rm ph}^{\rm (mn)} = \frac{\frac{c}{\sqrt{\epsilon_{\rm r}\mu_{\rm r}}}}{\sqrt{1 - \left(\frac{f_{\rm c}^{\rm (mn)}}{f}\right)^2}} \tag{5}$$

$$V_{\rm g}^{\rm (mn)} = \frac{c}{\sqrt{\epsilon_{\rm r}\mu_{\rm r}}} \sqrt{1 - \left(\frac{f_{\rm c}^{\rm (mn)}}{f}\right)^2} \tag{6}$$

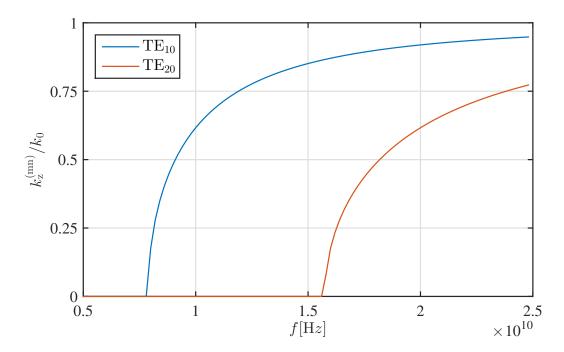


Figure 1: Normalized propagation constants in TE_{10} and TE_{20} modes.

1.4 Wave impedance

The wave impedance of a TE_{mn} mode is given by equation 7. This impedance is plotted for a TE_{10} wave in figure 3 for the unimodal frequency band.

$$W_{\rm mn}^{\rm TE} = \frac{\dot{E}_{\rm x}^{\rm (mn)}}{\dot{H}_{\rm y}^{\rm (mn)}} = \frac{\omega \mu_{\rm r} \mu_0}{k_{\rm z}^{\rm (mn)}} = \sqrt{\frac{\mu_{\rm r} \mu_0}{\epsilon_{\rm r} \epsilon_0}} \frac{1}{\sqrt{1 - \left(\frac{f_{\rm c}^{\rm (mn)}}{f}\right)^2}}$$
(7)

1.5 Cut-off frequencies in an ideal dielectric

The cut-off frequencies for a waveguide is given by equation 1. If the waveguide is filled with air, this corresponds to $\epsilon_{\rm r}=1$. When filled with a perfect dielectric, $\epsilon_{\rm r}$ changes value. However, it is still a real number.

The cut-off frequencies of a WR75 waveguide filled with a perfect dielectric, $\epsilon_{\rm r}=2.44,$ are shown in table 1.

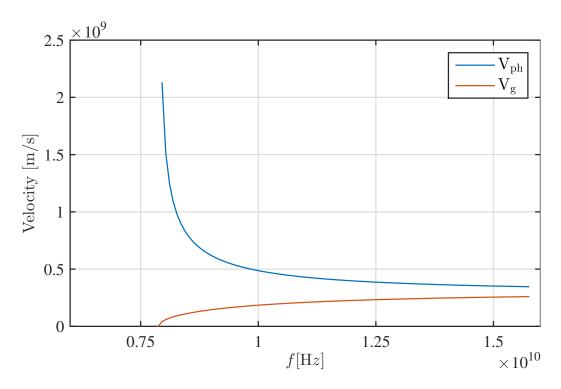


Figure 2: Phase and group velocities of TE_{10} wave in the unimodal frequency band

Table 1: Cut-off frequencies for waveguide filled with perfect dielectric

Mode	Cut-off frequency
TE_{10}	$5.0408\mathrm{GHz}$
TE_{20}	$10.082\mathrm{GHz}$

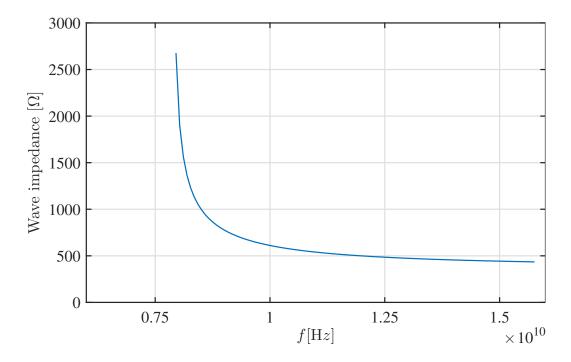


Figure 3: Wave impedance of TE_{10} wave in the unimodal frequency band

1.6 Dielectric loss constant

The dielectric loss constant for a mode TE_{mn} is given by equation 8.

$$\alpha_{\rm d}^{\rm (mn)} = \frac{\Delta \bar{P}_{\rm loss/unit}}{2\bar{P}} \approx \frac{\epsilon_{\rm r}^{"}}{\epsilon_{\rm r}^{'}} \frac{\pi}{\lambda} \left(\frac{\Lambda_{\rm mn}}{\lambda}\right) \tag{8}$$

 Λ_{mn} and λ are given by equations 9 and 10.

$$\Lambda_{\rm mn} = \frac{2\pi}{k_{\rm z}^{\rm (mn)}} = \frac{\lambda}{\sqrt{1 - \left(\frac{f_{\rm c}^{\rm (mn)}}{f}\right)^2}} \tag{9}$$

$$\lambda = \frac{2\pi}{k_0 \sqrt{\epsilon_{\rm r} \mu_{\rm r}}}.\tag{10}$$

According to [1],

$$\epsilon'' = \epsilon' \tan \delta = \epsilon_{\rm r} \epsilon_0 \tan \delta. \tag{11}$$

Given $\tan \delta = 0.002$, we have

$$\alpha_{\rm d}^{\rm (mn)} \approx \frac{k_0 \sqrt{\epsilon_{\rm r} \mu_{\rm r}}}{1000 \sqrt{1 - \left(\frac{f_c^{\rm (mn)}}{f}\right)^2}}.$$
 (12)

The dielectric loss constant is plotted for the unimodal frequency band in figure 4.

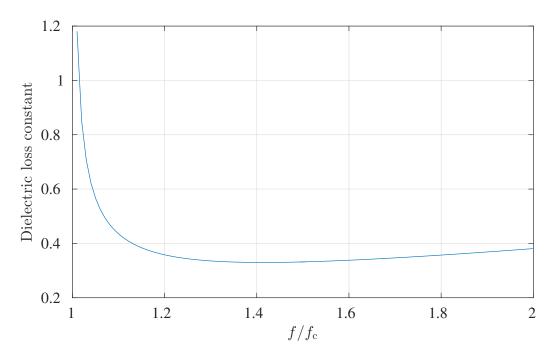


Figure 4: Dielectric loss constant, TE₁₀ wave.

1.7 Equivalent capacitance and inductance

The equivalent capacitance and equivalent inductance are given by equations 13 and 14, respectively.

$$C_{\text{equ}} \approx \frac{2k_{\text{z}}^{(10)}b}{\pi^2 f W_{10}^{\text{TE}}} \ln \left[\csc \left(\frac{\pi s}{2a} \right) \right]$$
 (13)

$$L_{\text{equ}} \approx \frac{a\mu_{\text{r}}\mu_{0}}{2\pi \cot^{2}\left(\frac{\pi s}{2a}\left[1 + \csc^{2}\left(\frac{\pi s}{2a}\right)\right]\right)}$$
(14)

The equivalent capacitance is plotted in figure 5.

The equivalent inductance does not vary with frequency. For the specified waveguide, $L_{\rm equ}\approx 2.1633\times 10^{-8}\,{\rm H/m}$.

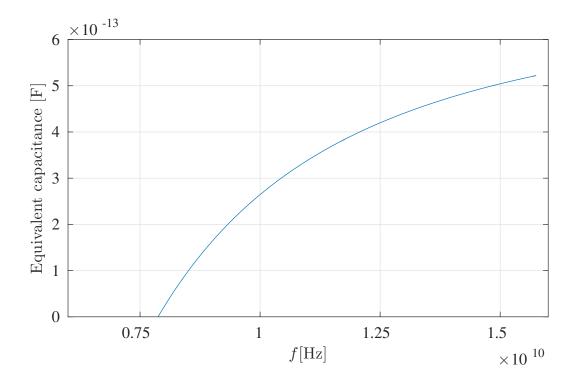


Figure 5: Equivalent capacitance over the unimodal frequency band.

2 Microstrip line

2.1 Effective permittivity

The effective permittivity relies on the geometry of the microstrip line. It is given by equation 15.

$$\epsilon_{\text{eff}}(f=0) = \left(\frac{\beta}{k_0}\right)^2 = \frac{\epsilon_{\text{r}} + 1}{2} + \frac{\epsilon_{\text{r}} - 1}{2\sqrt{1 + \frac{10h}{W}}}$$
(15)

Given the geometry $h=1\,\mathrm{mm}$ and $W=(0.1\ldots4)\,\mathrm{mm}$, with $\epsilon_\mathrm{r}=3.32$, the effective permittivity becomes as plotted in figure 6.

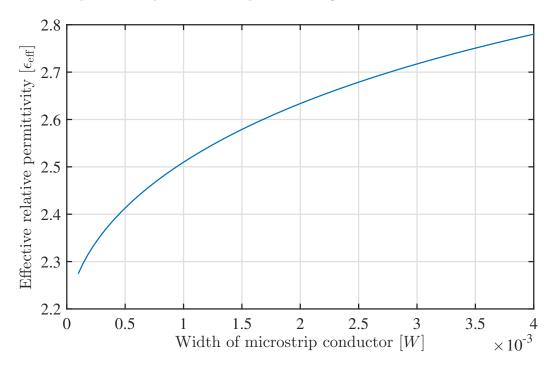


Figure 6: Effective relative permittivity of microstrip line.

2.2 Characteristic impedance

The characteristic impedance of a microstrip line is given by equation 16.

$$Z_{c} = \begin{cases} \frac{60}{\epsilon_{\text{eff}}(f=0)} \ln\left(\frac{8h}{W} + \frac{0.25W}{h}\right) & \frac{W}{h} < 1\\ \frac{120\pi}{\sqrt{\epsilon_{\text{eff}}(f=0)} \left[\frac{W}{h} + 1.393 + 0.667 \ln\left(\frac{W}{h} + 1.444\right)\right]} & \frac{W}{h} \ge 1 \end{cases}$$
(16)

Given the geometry $h=1\,\mathrm{mm}$ and $W=(0.1\ldots 4)\,\mathrm{mm}$, with $\epsilon_\mathrm{r}=3.32$, the characteristic impedance becomes as plotted in figure 7.

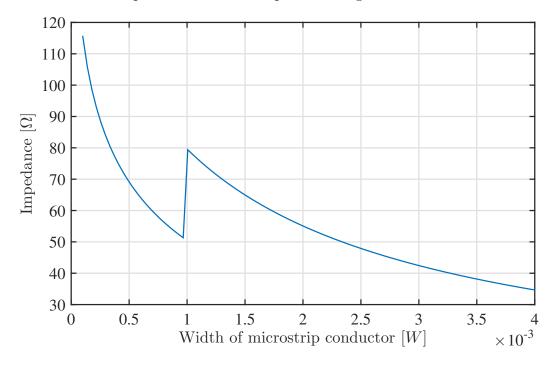


Figure 7: Characteristic impedance of microstrip line.

2.3 S-matrix coefficients

The S-matrix coefficients, transmission and reflection, are given by equations 17 and 18. They are plotted in figure 8.

$$T = \frac{2\sqrt{Z_{\rm c}^{(2)}Z_{\rm c}^{(1)}}}{Z_{\rm c}^{(2)} + Z_{\rm c}^{(1)}}$$
(17)

$$R = \frac{Z_{\rm c}^{(2)} - Z_{\rm c}^{(1)}}{Z_{\rm c}^{(2)} + Z_{\rm c}^{(1)}}$$
(18)

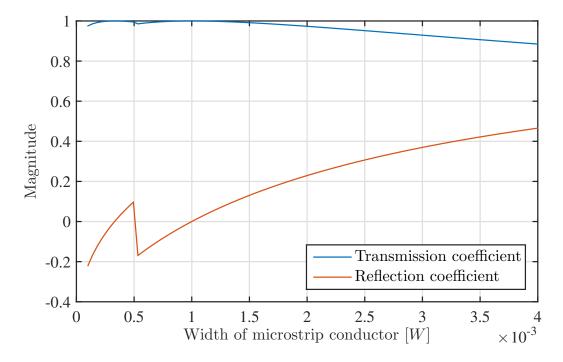


Figure 8: S-matrix coefficients of microstrip line.

3 Microstrip Branch-Line Directional Coupler

3.1 Calculating geometry of MS-BLDC

We want to design a Microstrip branch-line directional coupler with coupling and directivity ratios $-3 \, dB$ at the center frequency. The isolation ratio should be as low as possible.

The Keysight ADS tools can be used to calculate the geometry of a microstrip branch-line directional coupler. In order to use the ADS LineCalc utility, we have to obtain some parameters beforehand. These parameters are given by equations 19 and 20.

$$Z_{0,1} = Z_0 \sqrt{1 - k_c^2} \tag{19}$$

$$Z_{0,2} = \frac{Z_{0,1}}{\sqrt{1 - \left(\frac{Z_{0,1}}{Z_0}\right)^2}} \tag{20}$$

Here $k_{\rm c}$ is given by

$$k_{\rm c} = \sqrt{\frac{P_{\rm c}}{P_{\rm i}}} = \sqrt{\frac{1}{2}} \tag{21}$$

where P_i is the incident power and P_c is the power in the coupled port. We also have to take into account that port 1, port 2 and port 4 are all a quarter wavelength away from each other. Therefore, ideally, the power on port 2 and 4 should be 90° out of phase. We shall examine this closer later.

Inserting the values in table 2 into ADS LineCalc, the results in table 3 are obtained.

Table 2: ADS LineCalc input parameters

Parameter	Size
F_0	$1.6\mathrm{GHz}$
h	$1\mathrm{mm}$
$\epsilon_{ m r}$	3.32
Z_0	50Ω
$Z_{0,1}$	35.3553Ω
$Z_{0,2}$	50.0000Ω
$\Delta\phi$	90°

Table 3: Branch-line coupler geometry

Parameter	Size
L50	28.8218 mm
W50	$2.33717\mathrm{mm}$
L1	$28.2112\mathrm{mm}$
W1	$3.91089\mathrm{mm}$
L2	$28.8170{ m mm}$
W2	$2.34683\mathrm{mm}$

3.2 Simulation of MS-BLDC

Figure 9 shows a model of the MS-BLDC in ADS.

Figure 10 shows a simulation of S(2,1) and S(4,1) in ADS. The markers indicate the peak values. We see that the components are in fact not exactly

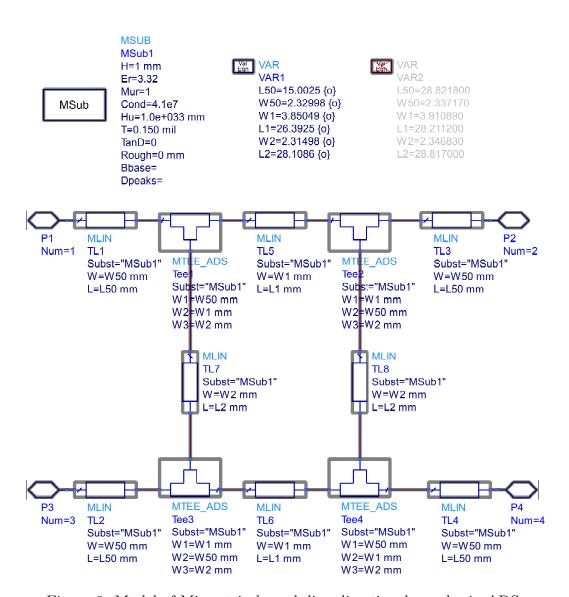


Figure 9: Model of Microstrip branch-line directional coupler in ADS.

 $-3 \,\mathrm{dB}$ at 1.6 GHz. As can be seen from figure 11, the two components are approximately 90° out of phase.

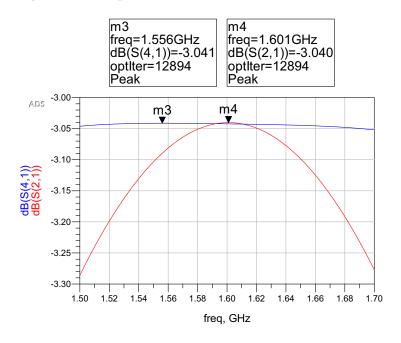


Figure 10: Simulated S-matrix components S(2,1) and S(4,1).

3.3 In-depth electromagnetic simulation

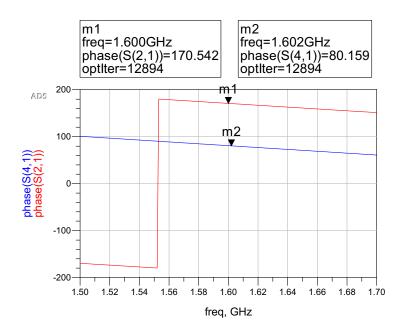


Figure 11: Simulated S(2,1) and S(4,1) phase difference.

References

[1] larebok mikrobolge